Data Sheel

2N5306 2N5308



Manufacturers of World Class Discrete Semiconductors

NPN SILICON DARLINGTON TRANSISTOR

JEDEC TO-92 CASE (ECB)

DESCRIPTION

The CENTRAL SEMICONDUCTOR 2N5306, 2N5308 types are NPN Silicon Epitaxial Planar Darlington Transistors designed for high gain amplifier applications.

<u>MAXIMUM RATINGS</u> $(T_A = 25^{\circ}C)$

$\underline{MAXIMUM RATINGS} (I_A = 25°C)$	SYMBOL	<u>2N5306</u>	<u>2N5308</u>	<u>UNITS</u>
Collector-Base Voltage	V _{CBO}	25	40	v
Collector-Emitter Voltage	V _{CEO}	25	40	V
Emitter-Base Voltage	V _{EBO}	12		V
Continuous Collector Current	۱ _C	300)	mA
Peak Collector Current	СМ	500)	mA
Continuous Base Current	Ι _Β	50	C	mA
Power Dissipation	PD	625	ō	mW
Power Dissipation (T _C =25°C)	PD	1.5	5	W
Operating and Storage				
Junction Temperature	T _J ,T _{stg}	-65 to +	150	°C
Thermal Resistance	Θ_{JA}	200)	°C/W
Thermal Resistance	ΘJ _C	83.3	3	°C/W

<u>ELECTRICAL CHARACTERISTICS</u> ($T_A = 25^{\circ}C$ unless otherwise noted)

		<u>2N5</u>	<u>5306</u>	<u>2N5</u>	308	
SYMBOL	TEST CONDITIONS	MIN	MAX	MIN	MAX	UNITS
Ісво	V _{CB} =Rated V _{CBO}		100		100	nA
ICBO	V _{CB} =Rated V _{CBO} , T _A =100°C		20		20	μA
IEBO	$V_{EB} = 12V$		100		100	nA
BVCBO	$I_{\rm C} = 100 \rm nA$	25		40		V
BVCEO	$I_{C} = 10 \text{mA}$	25		40		V
BVEBO	I _F = 100nA	12		12		V
V _{CE} (SAT)	$I_{C} = 200 \text{mA}, I_{B} = 0.2 \text{mA}$		1.4		1.4	V
V _{BE} (SAT)	$I_{C} = 200 \text{mA}, I_{B} = 0.2 \text{mA}$		1.6		1.6	V
V _{BE(ON)}	$V_{CF} = 5.0V, I_{C} = 200 \text{mA}$		1.5		1.5	V
h _{FE}	$V_{CE} = 5.0V, I_{C} = 2.0mA$	7K	70K	7K	70K	
h _{FE}	$V_{CE} = 5.0V, I_{C} = 100mA$	20K		20K		

(Continued on Reverse Side)

ELECTRICAL CHARACTERISTICS (Continued)

SYMBOL	TEST CONDITIONS	MIN <u>TYP</u>	MAX	UNITS
h _{fe}	$V_{CE} = 5.0V, I_{C} = 2.0mA, f = 1.0kHz$	7К		
h _{fe}	$V_{CE} = 5.0V, I_{C} = 2.0mA, f = 10MHz$	15.6		dB
fŢ	$V_{CE} = 5.0V, I_{C} = 2.0mA, f = 10MHz$	60		MHz
h _{ie}	$V_{CE} = 5.0V, I_{C} = 2.0mA, f = 1.0kHz$	650		kW
C _{cb}	$V_{CB} = 10V, f = 1.0MHz$		10	pF
C _{eb}	$V_{EB} = 0.5V, f = 1.0MHz$	12		pF



145 Adams Avenue Hauppauge, NY 11788 USA Tel: (631) 435-1110 • Fax: (631) 435-1824 www.centralsemi.com

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CONTACT US

Corporate Headquarters & Customer Support Team

Central Semiconductor Corp. 145 Adams Avenue Hauppauge, NY 11788 USA Main Tel: (631) 435-1110 Main Fax: (631) 435-1824 Support Team Fax: (631) 435-3388 www.centralsemi.com

Worldwide Field Representatives: www.centralsemi.com/wwreps

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